

LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCTS CHARACTERISTICS

| | |
|----------------------------|-----------------|
| I_{F(AV)} | 2 x 15 A |
| V_{RRM} | 45 V |
| T_{j (max)} | 150 °C |
| V_{F (max)} | 0.50 V |

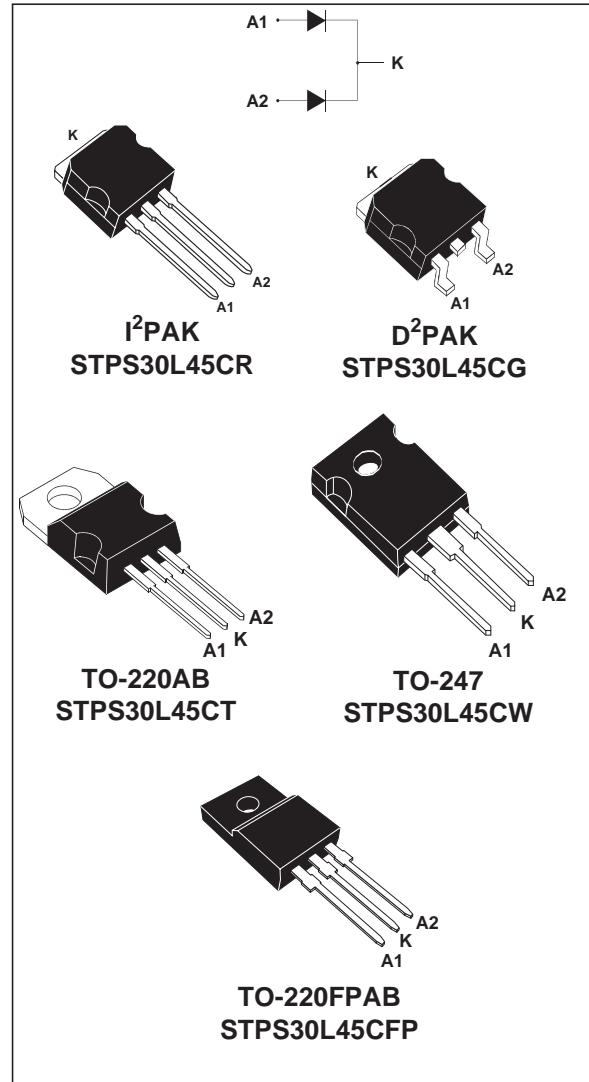
FEATURES AND BENEFITS

- LOW FORWARD VOLTAGE DROP MEANING VERY SMALL CONDUCTION LOSSES
- LOW SWITCHING LOSSES ALLOWING HIGH FREQUENCY OPERATION
- LOW THERMAL RESISTANCE
- AVALANCHE RATED
- INSULATED PACKAGE: TO-220FPAB
Insulating voltage: 2000V DC
Capacitance = 45pF
- AVALANCHE CAPABILITY SPECIFIED

DESCRIPTION

Dual center tap schottky rectifiers suited for Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in TO-247, TO-220AB, TO-220FPAB, D²PAK and I²PAK these devices are intended for use in low voltage, high frequency inverters, free-wheeling and polarity protection applications.



STPS30L45CG/CR/CT/CW/CFP

ABSOLUTE RATINGS (limiting values, per diode)

| Symbol | Parameter | | | | Value | Unit | | | |
|---------------------|------------------------------------------|-------------------------------------------------------------|-----------------------------------|-------------------------|---------------|------|--|--|--|
| V _{RRM} | Repetitive peak reverse voltage | | | | 45 | V | | | |
| I _{F(RMS)} | RMS forward current | | | | 30 | A | | | |
| I _{F(AV)} | Average forward current | TO-220FPAB | T _c = 110°C δ = 0.5 | Per diode Per device | 15 30 | A | | | |
| | | TO-220AB, TO-247, I ² PAK, D ² PAK | T _c = 135°C δ = 0.5 | | | | | | |
| I _{FSM} | Surge non repetitive forward current | | tp = 10 ms Sinusoidal | | 220 | A | | | |
| I _{IRRM} | Repetitive peak reverse current | | tp = 2 μs square F=1kHz | | 1 | A | | | |
| I _{IRSM} | Non repetitive peak reverse current | | tp = 100 μs square | | 3 | A | | | |
| P _{ARM} | Repetitive peak avalanche power | | tp = 1μs T _j = 25°C | | 6000 | W | | | |
| T _{stg} | Storage temperature range | | | | - 65 to + 150 | °C | | | |
| T _j | Maximum operating junction temperature * | | | | 150 | °C | | | |
| dV/dt | Critical rate of rise of reverse voltage | | | | 10000 | V/μs | | | |

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th}(j - a)}$ thermal runaway condition for a diode on its own heatsink

THERMAL RESISTANCES

| Symbol | Parameter | | | Value | Unit |
|-----------------------|------------------|-------------------------------------------------------------|--------------------|--------------|------|
| R _{th} (j-c) | Junction to case | TO-220FPAB | Per diode Total | 4 3.2 | °C/W |
| | | TO-220AB, TO-247, I ² PAK, D ² PAK | Per diode Total | 1.60 0.85 | |
| R _{th} (c) | | TO-220FPAB | Coupling | 2.5 | °C/W |
| | | TO-220AB, TO-247, I ² PAK, D ² PAK | | 0.10 | |

When the diodes 1 and 2 are used simultaneously :
 $\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$

STATIC ELECTRICAL CHARACTERISTICS (per diode)

| Symbol | Parameter | Tests Conditions | | Min. | Typ. | Max. | Unit |
|------------------|-------------------------|------------------------|-----------------------------------|------|------|------|------|
| I _R * | Reverse leakage current | T _j = 25°C | V _R = V _{RRM} | | | 0.4 | mA |
| | | T _j = 125°C | | | 100 | 200 | mA |
| V _F * | Forward voltage drop | T _j = 25°C | I _F = 15 A | | | 0.55 | V |
| | | T _j = 125°C | I _F = 15 A | | 0.42 | 0.50 | |
| | | T _j = 25°C | I _F = 30 A | | | 0.74 | |
| | | T _j = 125°C | I _F = 30 A | | 0.59 | 0.67 | |

Pulse test : * tp = 380 μs, δ < 2%

To evaluate the conduction losses use the following equation :
 $P = 0.330 \times I_{F(AV)} + 0.011 I_{F(RMS)}^2$

Fig. 1: Average forward power dissipation versus average forward current (per diode).

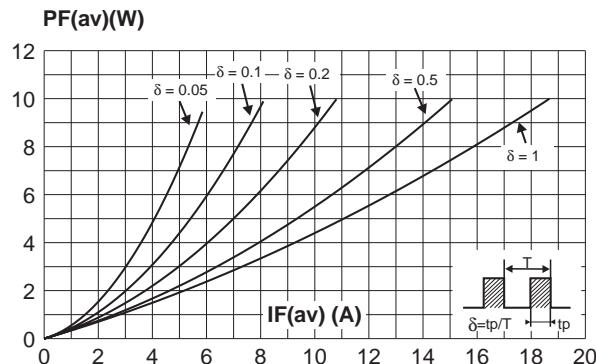


Fig. 2: Average forward current versus ambient temperature ($\delta=0.5$, per diode).

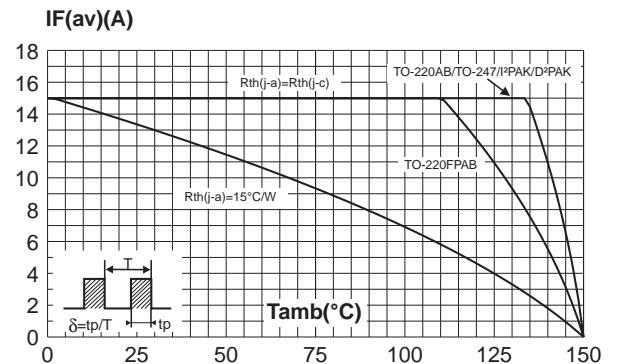


Fig. 3: Normalized avalanche power derating versus pulse duration.

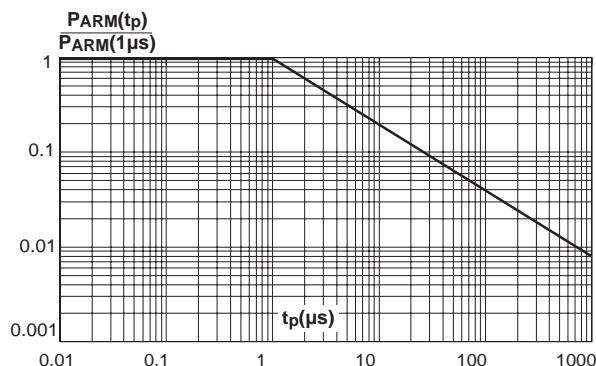


Fig. 4: Normalized avalanche power derating versus junction temperature.

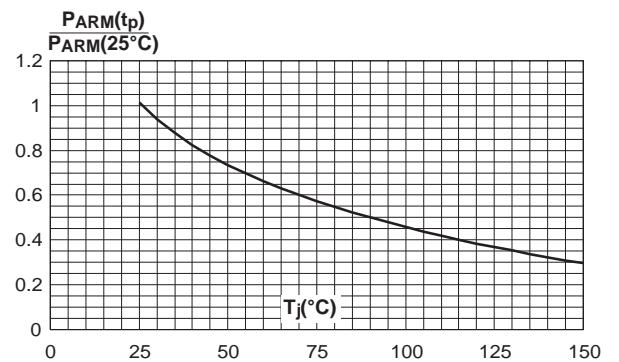


Fig. 5-1: Non repetitive surge peak forward current versus overload duration (maximum values, per diode).

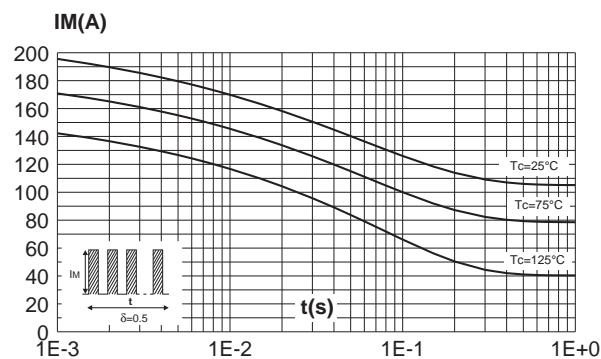
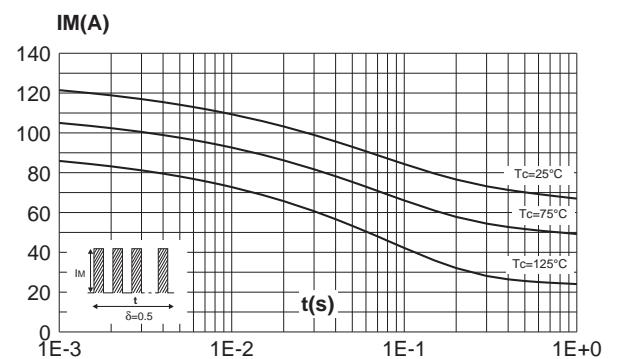
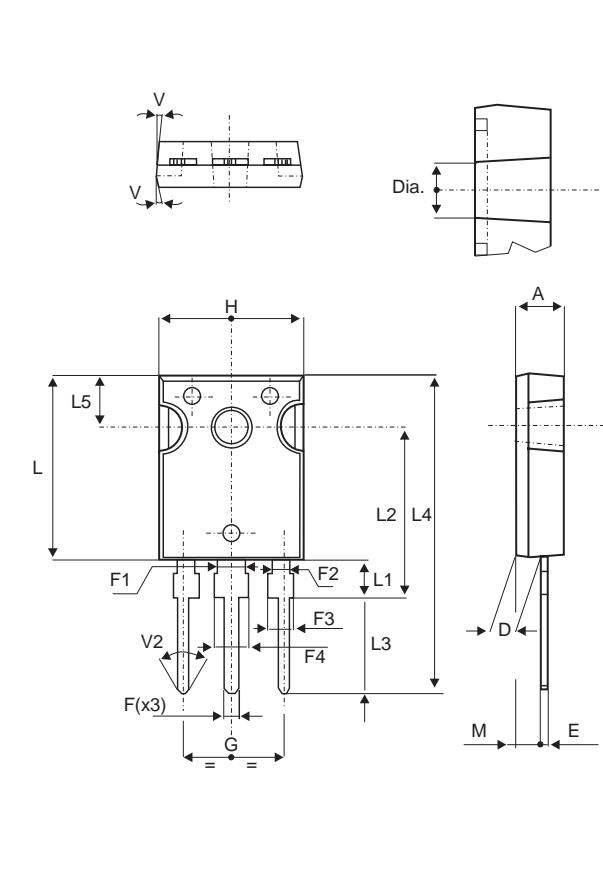


Fig. 5-2: Non repetitive surge peak forward current versus overload duration (maximum values, per diode) (TO-220FPAB only).



STPS30L45CG/CR/CT/CW/CFP

PACKAGE MECHANICAL DATA TO-247



| REF. | DIMENSIONS | | | | | |
|------|-------------|-------|-------|--------|-------|-------|
| | Millimeters | | | Inches | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.85 | | 5.15 | 0.191 | | 0.203 |
| D | 2.20 | | 2.60 | 0.086 | | 0.102 |
| E | 0.40 | | 0.80 | 0.015 | | 0.031 |
| F | 1.00 | | 1.40 | 0.039 | | 0.055 |
| F1 | | 3.00 | | | 0.118 | |
| F2 | | 2.00 | | | 0.078 | |
| F3 | 2.00 | | 2.40 | 0.078 | | 0.094 |
| F4 | 3.00 | | 3.40 | 0.118 | | 0.133 |
| G | | 10.90 | | | 0.429 | |
| H | 15.45 | | 15.75 | 0.608 | | 0.620 |
| L | 19.85 | | 20.15 | 0.781 | | 0.793 |
| L1 | 3.70 | | 4.30 | 0.145 | | 0.169 |
| L2 | | 18.50 | | | 0.728 | |
| L3 | 14.20 | | 14.80 | 0.559 | | 0.582 |
| L4 | | 34.60 | | | 1.362 | |
| L5 | | 5.50 | | | 0.216 | |
| M | 2.00 | | 3.00 | 0.078 | | 0.118 |
| V | | 5° | | | 5° | |
| V2 | | 60° | | | 60° | |
| Dia. | 3.55 | | 3.65 | 0.139 | | 0.143 |

- Cooling method : C
- Recommended torque value : 0.8m.N
- Maximum torque value : 1.0m.N

| Ordering type | Marking | Package | Weight | Base qty | Delivery mode |
|----------------|--------------|--------------------|--------|----------|---------------|
| STPS30L45CT | STPS30L45CT | TO-220AB | 2g | 50 | Tube |
| STPS30L45CG | STPS30L45CG | D ² PAK | 1.8g | 50 | Tube |
| STPS30L45CG-TR | STPS30L45CG | D ² PAK | 1.8g | 500 | Tape & reel |
| STPS30L45CW | STPS30L45CW | TO-247 | 4.4g | 30 | Tube |
| STPS30L45CR | STPS30L45CR | I ² PAK | 1.4g | 50 | Tube |
| STPS30L45CFP | STPS30L45CFP | TO-220FPAB | 1.9 g | 50 | Tube |

- Epoxy meets UL94,V0